

IPG20N06S4L11ATMA1

IPG20N06S4L11ATMA1 Information

Heisener.com	 IPG20N06S4L11ATMA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CH 8TDSON 8-PowerVDFN For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPG20N06S4L11ATMA1 Specifications

Manufacturer Part Number	IPG20N06S4L11ATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-PowerVDFN
Series	Automotive, AEC-Q101, OptiMOS?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	20A
Rds On (Max) @ Id, Vgs	11.2 mOhm @ 17A, 10V
Vgs(th) (Max) @ Id	2.2V @ 28µA
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4020pF @ 25V
Power - Max	65W
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-PowerVDFN
Supplier Device Package	PG-TDSON-8-4
	Report errors?

IPG20N06S4L11ATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPG20N06S4L11ATMA1 Payment Methods





If you have any question about IPG20N06S4L11ATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com